

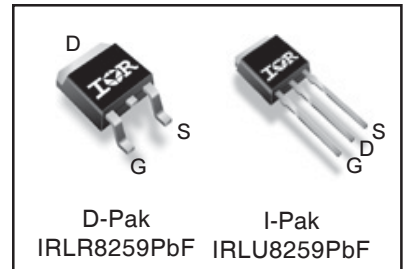
### Applications

- High Frequency Synchronous Buck Converters for Computer Processor Power
- High Frequency Isolated DC-DC Converters with Synchronous Rectification for Telecom and Industrial Use

| $V_{DS}$ | $R_{DS(on)}$ max | Qg    |
|----------|------------------|-------|
| 25V      | 8.7mΩ            | 6.8nC |

### Benefits

- Very Low RDS(on) at 4.5V  $V_{GS}$
- Ultra-Low Gate Impedance
- Fully Characterized Avalanche Voltage and Current
- Lead-Free
- RoHS compliant



| G    | D     | S      |
|------|-------|--------|
| Gate | Drain | Source |

### Absolute Maximum Ratings

|                                   | Parameter                                | Max.                  | Units |
|-----------------------------------|------------------------------------------|-----------------------|-------|
| $V_{DS}$                          | Drain-to-Source Voltage                  | 25                    | V     |
| $V_{GS}$                          | Gate-to-Source Voltage                   | ± 20                  |       |
| $I_D$ @ $T_C = 25^\circ\text{C}$  | Continuous Drain Current, $V_{GS}$ @ 10V | 57 <sup>④</sup>       | A     |
| $I_D$ @ $T_C = 100^\circ\text{C}$ | Continuous Drain Current, $V_{GS}$ @ 10V | 40 <sup>④</sup>       |       |
| $I_{DM}$                          | Pulsed Drain Current <sup>①</sup>        | 230                   |       |
| $P_D$ @ $T_C = 25^\circ\text{C}$  | Maximum Power Dissipation <sup>⑤</sup>   | 48                    | W     |
| $P_D$ @ $T_C = 100^\circ\text{C}$ | Maximum Power Dissipation <sup>⑤</sup>   | 24                    |       |
|                                   | Linear Derating Factor                   | 0.32                  | W/°C  |
| $T_J$                             | Operating Junction and                   | -55 to + 175          | °C    |
| $T_{STG}$                         | Storage Temperature Range                |                       |       |
|                                   | Soldering Temperature, for 10 seconds    | 300 (1.6mm from case) |       |

### Thermal Resistance

|                 | Parameter                                    | Typ. | Max. | Units |
|-----------------|----------------------------------------------|------|------|-------|
| $R_{\theta JC}$ | Junction-to-Case                             | —    | 3.15 | °C/W  |
| $R_{\theta JA}$ | Junction-to-Ambient (PCB Mount) <sup>⑥</sup> | —    | 50   |       |
| $R_{\theta JA}$ | Junction-to-Ambient                          | —    | 110  |       |

#### ORDERING INFORMATION:

See detailed ordering and shipping information on the last page of this data sheet.

Notes <sup>①</sup> through <sup>⑥</sup> are on page 11

Static @  $T_J = 25^\circ\text{C}$  (unless otherwise specified)

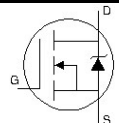
|                                | Parameter                                  | Min. | Typ. | Max. | Units      | Conditions                                                                         |
|--------------------------------|--------------------------------------------|------|------|------|------------|------------------------------------------------------------------------------------|
| $BV_{DSS}$                     | Drain-to-Source Breakdown Voltage          | 25   | —    | —    | V          | $V_{GS} = 0V, I_D = 250\mu A$                                                      |
| $\Delta BV_{DSS}/\Delta T_J$   | Breakdown Voltage Temp. Coefficient        | —    | 18   | —    | mV/°C      | Reference to $25^\circ\text{C}, I_D = 1mA$                                         |
| $R_{DS(on)}$                   | Static Drain-to-Source On-Resistance       | —    | 6.3  | 8.7  | m $\Omega$ | $V_{GS} = 10V, I_D = 21A$ ③                                                        |
|                                |                                            | —    | 10.6 | 12.9 |            | $V_{GS} = 4.5V, I_D = 17A$ ③                                                       |
| $V_{GS(th)}$                   | Gate Threshold Voltage                     | 1.35 | 1.90 | 2.35 | V          | $V_{DS} = V_{GS}, I_D = 25\mu A$                                                   |
| $\Delta V_{GS(th)}/\Delta T_J$ | Gate Threshold Voltage Coefficient         | —    | -7.1 | —    | mV/°C      |                                                                                    |
| $I_{DSS}$                      | Drain-to-Source Leakage Current            | —    | —    | 1.0  | $\mu A$    | $V_{DS} = 20V, V_{GS} = 0V$                                                        |
|                                |                                            | —    | —    | 150  |            | $V_{DS} = 20V, V_{GS} = 0V, T_J = 125^\circ\text{C}$                               |
| $I_{GSS}$                      | Gate-to-Source Forward Leakage             | —    | —    | 100  | nA         | $V_{GS} = 20V$                                                                     |
|                                | Gate-to-Source Reverse Leakage             | —    | —    | -100 |            | $V_{GS} = -20V$                                                                    |
| $g_{fs}$                       | Forward Transconductance                   | 55   | —    | —    | S          | $V_{DS} = 13V, I_D = 17A$                                                          |
| $Q_g$                          | Total Gate Charge                          | —    | 6.8  | 10   | nC         | $V_{DS} = 13V$<br>$V_{GS} = 4.5V$<br>$I_D = 17A$<br>See Fig. 16                    |
| $Q_{gs1}$                      | Pre-V <sub>th</sub> Gate-to-Source Charge  | —    | 1.5  | —    |            |                                                                                    |
| $Q_{gs2}$                      | Post-V <sub>th</sub> Gate-to-Source Charge | —    | 1.1  | —    |            |                                                                                    |
| $Q_{gd}$                       | Gate-to-Drain Charge                       | —    | 2.4  | —    |            |                                                                                    |
| $Q_{godr}$                     | Gate Charge Overdrive                      | —    | 1.8  | —    |            |                                                                                    |
| $Q_{sw}$                       | Switch Charge ( $Q_{gs2} + Q_{gd}$ )       | —    | 3.5  | —    |            |                                                                                    |
| $Q_{oss}$                      | Output Charge                              | —    | 5.9  | —    | nC         | $V_{DS} = 16V, V_{GS} = 0V$                                                        |
| $R_G$                          | Gate Resistance                            | —    | 2.2  | 3.6  | $\Omega$   |                                                                                    |
| $t_{d(on)}$                    | Turn-On Delay Time                         | —    | 8.4  | —    | ns         | $V_{DD} = 13V, V_{GS} = 4.5V$ ③<br>$I_D = 17A$<br>$R_G = 1.8\Omega$<br>See Fig. 14 |
| $t_r$                          | Rise Time                                  | —    | 38   | —    |            |                                                                                    |
| $t_{d(off)}$                   | Turn-Off Delay Time                        | —    | 9.1  | —    |            |                                                                                    |
| $t_f$                          | Fall Time                                  | —    | 8.9  | —    |            |                                                                                    |
| $C_{iss}$                      | Input Capacitance                          | —    | 900  | —    | pF         | $V_{GS} = 0V$<br>$V_{DS} = 13V$<br>$f = 1.0MHz$                                    |
| $C_{oss}$                      | Output Capacitance                         | —    | 300  | —    |            |                                                                                    |
| $C_{rss}$                      | Reverse Transfer Capacitance               | —    | 110  | —    |            |                                                                                    |

## Avalanche Characteristics

|          | Parameter                       | Typ. | Max. | Units |
|----------|---------------------------------|------|------|-------|
| $E_{AS}$ | Single Pulse Avalanche Energy ② | —    | 67   | mJ    |
| $I_{AR}$ | Avalanche Current ①             | —    | 17   | A     |
| $E_{AR}$ | Repetitive Avalanche Energy ①   | —    | 4.8  | mJ    |

## Diode Characteristics

|          | Parameter                              | Min.                                                                 | Typ. | Max. | Units | Conditions                                                     |
|----------|----------------------------------------|----------------------------------------------------------------------|------|------|-------|----------------------------------------------------------------|
| $I_S$    | Continuous Source Current (Body Diode) | —                                                                    | —    | 56 ④ | A     | MOSFET symbol showing the integral reverse p-n junction diode. |
| $I_{SM}$ | Pulsed Source Current (Body Diode) ①   | —                                                                    | —    | 230  |       |                                                                |
| $V_{SD}$ | Diode Forward Voltage                  | —                                                                    | —    | 1.0  | V     | $T_J = 25^\circ\text{C}, I_S = 17A, V_{GS} = 0V$ ③             |
| $t_{rr}$ | Reverse Recovery Time                  | —                                                                    | 17   | 26   | ns    | $T_J = 25^\circ\text{C}, I_F = 17A, V_{DD} = 13V$              |
| $Q_{rr}$ | Reverse Recovery Charge                | —                                                                    | 15   | 23   | nC    | $di/dt = 200A/\mu s$ ③                                         |
| $t_{on}$ | Forward Turn-On Time                   | Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD) |      |      |       |                                                                |



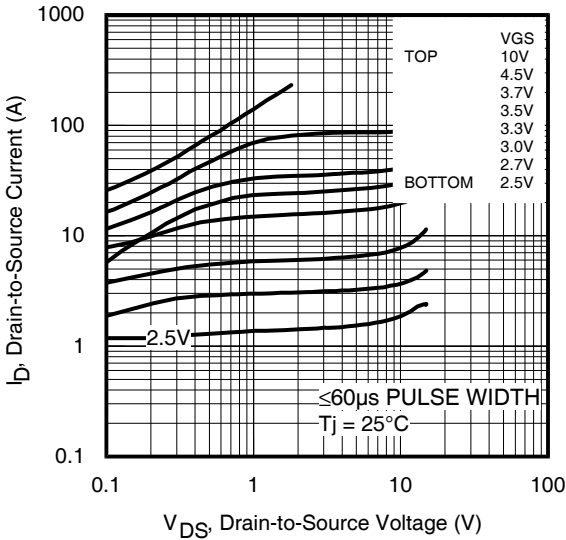


Fig 1. Typical Output Characteristics

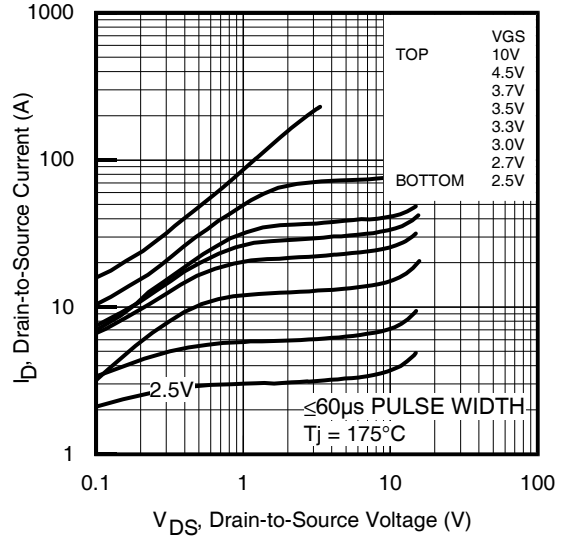


Fig 2. Typical Output Characteristics

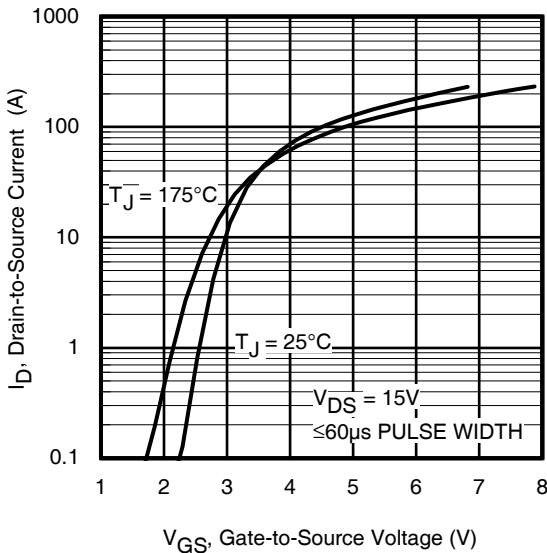


Fig 3. Typical Transfer Characteristics

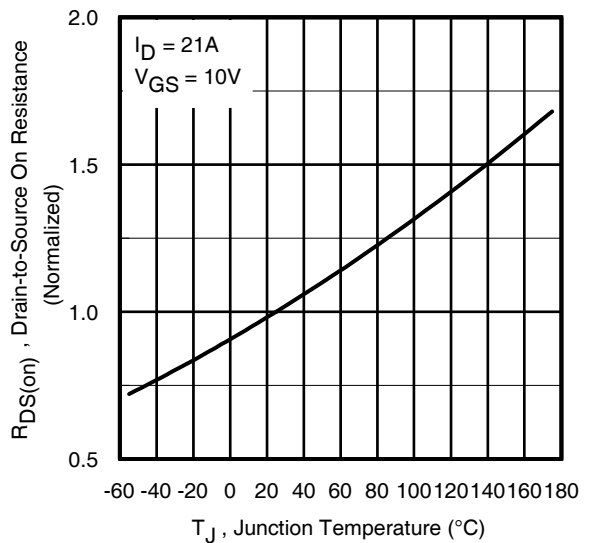
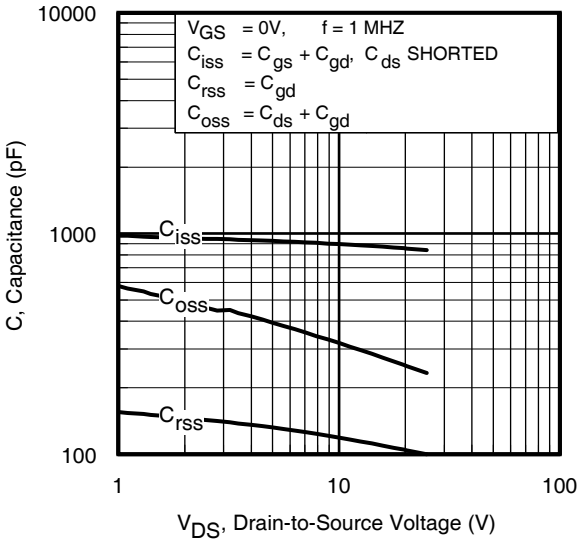
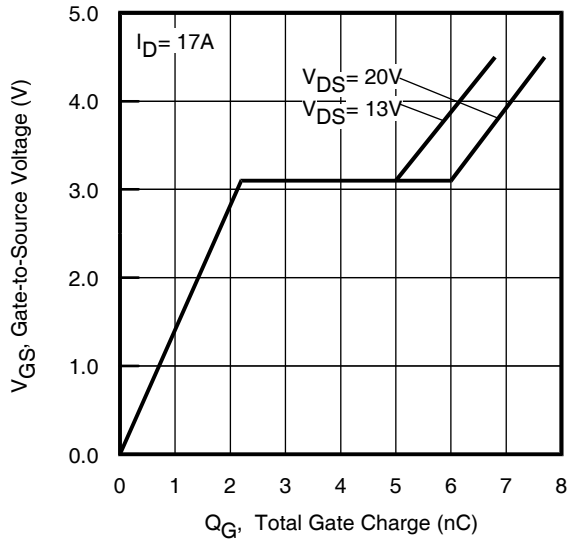


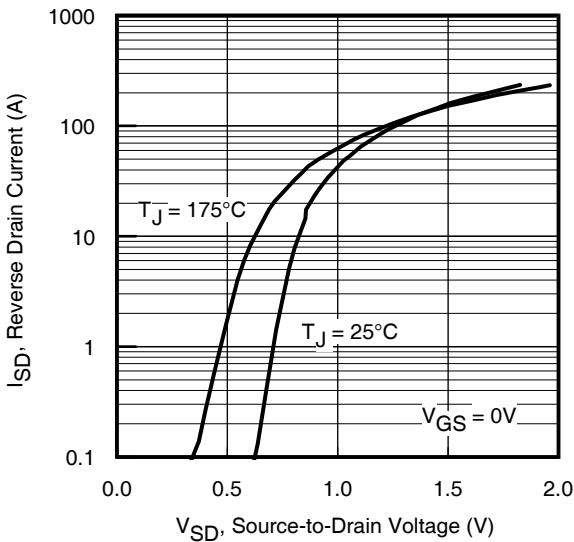
Fig 4. Normalized On-Resistance vs. Temperature



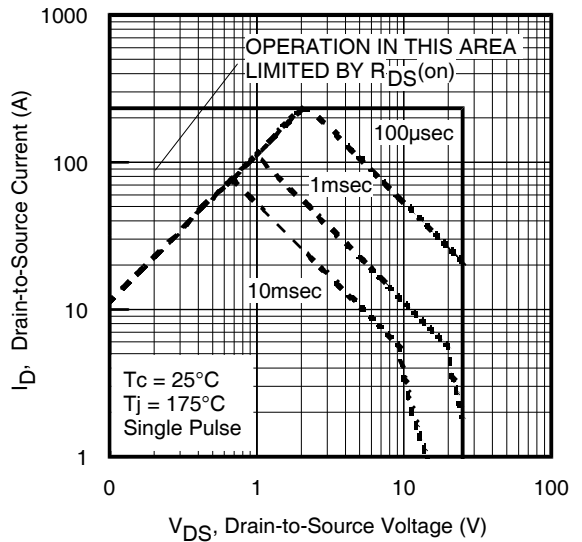
**Fig 5.** Typical Capacitance vs. Drain-to-Source Voltage



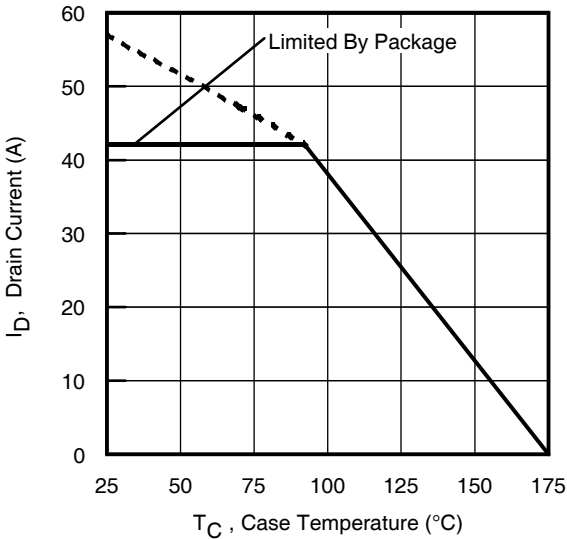
**Fig 6.** Typical Gate Charge vs. Gate-to-Source Voltage



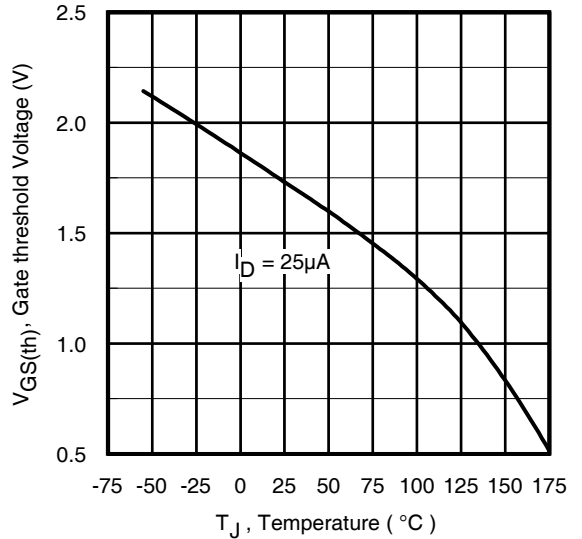
**Fig 7.** Typical Source-Drain Diode Forward Voltage



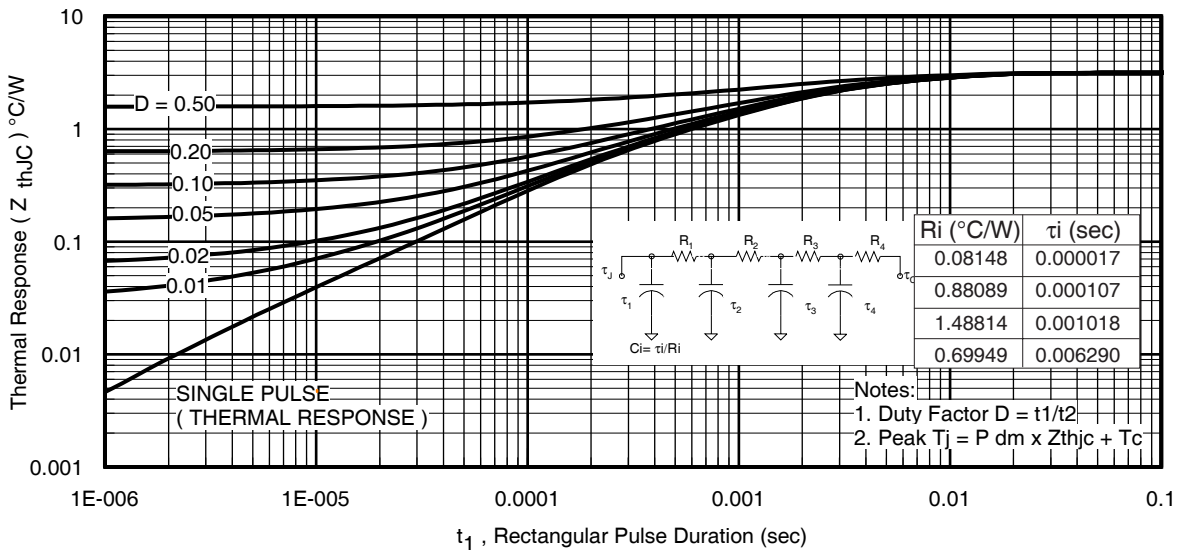
**Fig 8.** Maximum Safe Operating Area



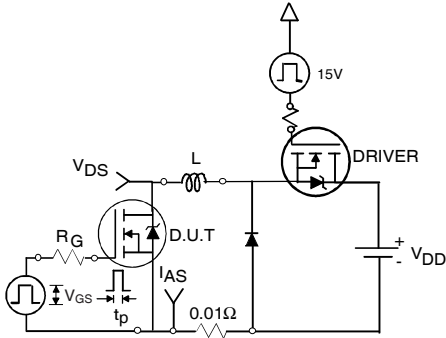
**Fig 9.** Maximum Drain Current vs. Case Temperature



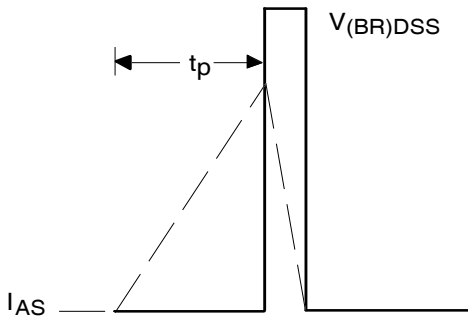
**Fig 10.** Threshold Voltage vs. Temperature



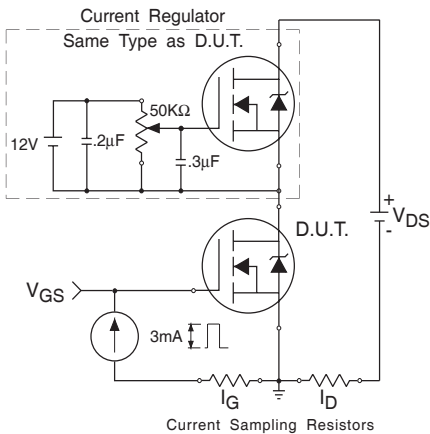
**Fig 11.** Maximum Effective Transient Thermal Impedance, Junction-to-Case



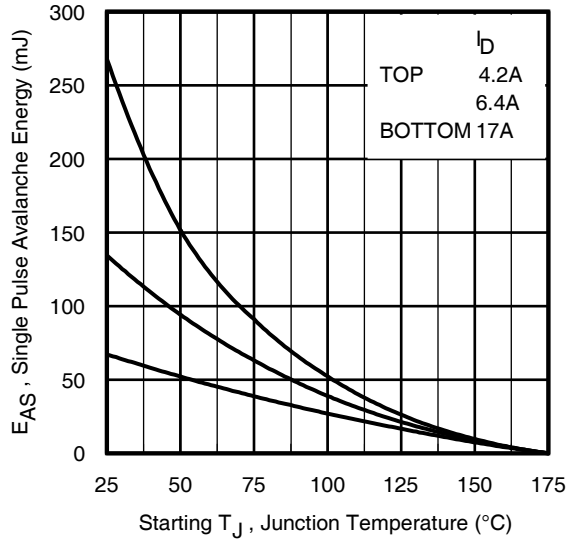
**Fig 12a.** Unclamped Inductive Test Circuit



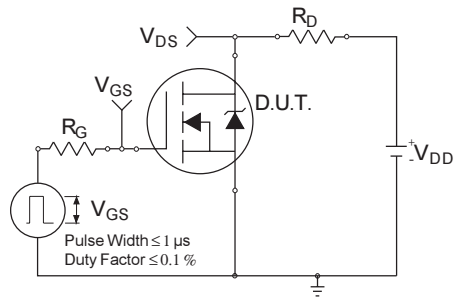
**Fig 12b.** Unclamped Inductive Waveforms



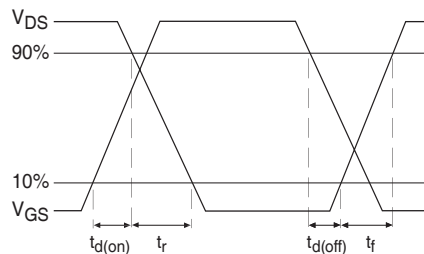
**Fig 13.** Gate Charge Test Circuit



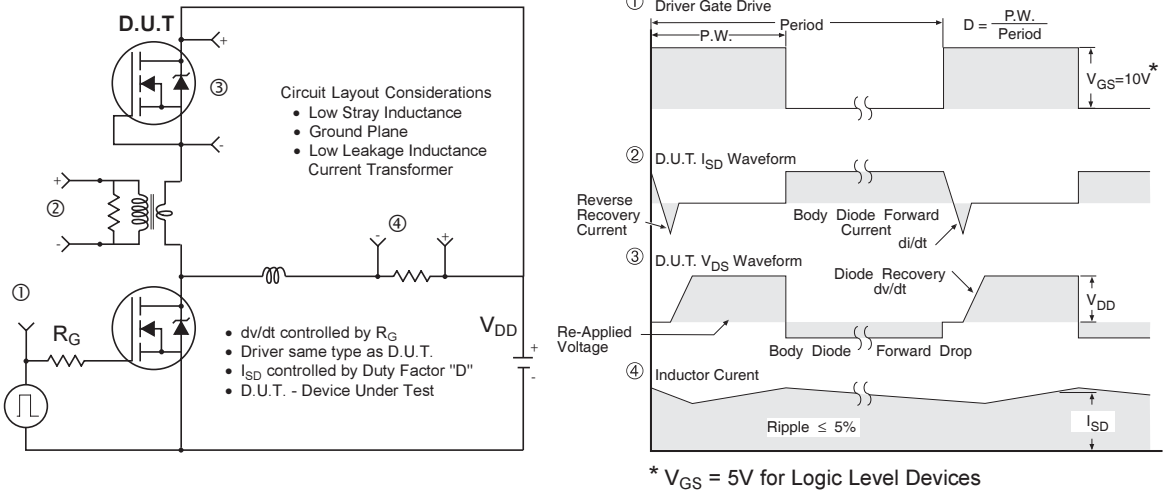
**Fig 12c.** Maximum Avalanche Energy vs. Drain Current



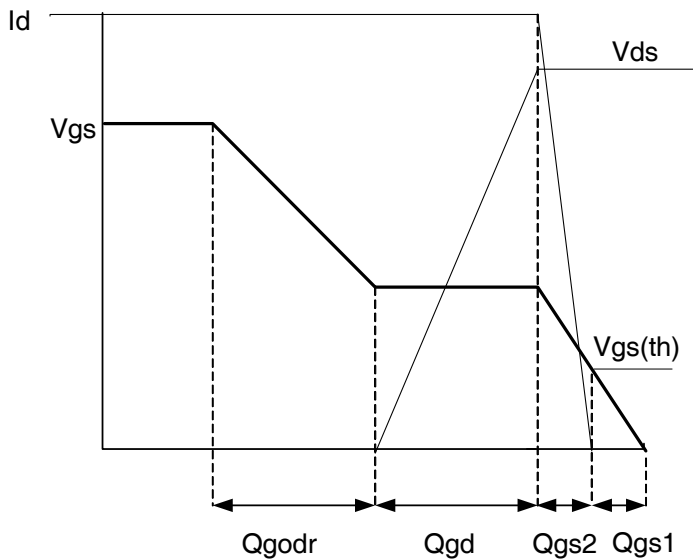
**Fig 14a.** Switching Time Test Circuit



**Fig 14b.** Switching Time Waveforms



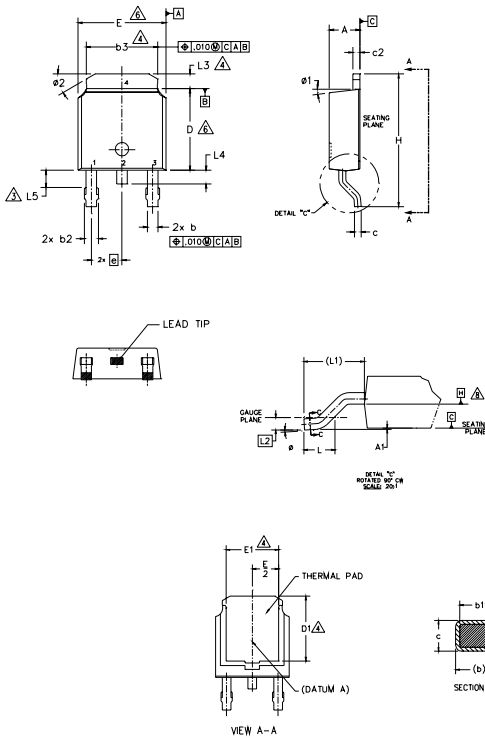
**Fig 15. Peak Diode Recovery  $dv/dt$  Test Circuit for N-Channel HEXFET<sup>®</sup> Power MOSFETs**



**Fig 16. Gate Charge Waveform**

## D-Pak (TO-252AA) Package Outline

Dimensions are shown in millimeters (inches)



**NOTES:**

- 1.- DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994
- 2.- DIMENSION ARE SHOWN IN INCHES [MILLIMETERS]
- △ LEAD DIMENSION UNCONTROLLED IN L5.
- △ DIMENSION D1, E1, L3 & b3 ESTABLISH A MINIMUM MOUNTING SURFACE FOR THERMAL PAD.
- 5.- SECTION C-C DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN .005 AND 0.10 [0.13 AND 0.25] FROM THE LEAD TIP.
- △ DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED .005 [0.13] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.
- △ DIMENSION b1 & c1 APPLIED TO BASE METAL ONLY.
- △ DATUM A & B TO BE DETERMINED AT DATUM PLANE H.
- 9.- OUTLINE CONFORMS TO JEDEC OUTLINE TO-252AA.

| SYMBOL | DIMENSIONS  |       |           |      | NOTES |
|--------|-------------|-------|-----------|------|-------|
|        | MILLIMETERS |       | INCHES    |      |       |
|        | MIN.        | MAX.  | MIN.      | MAX. |       |
| A      | 2.18        | 2.39  | .086      | .094 |       |
| A1     | -           | 0.13  | -         | .005 |       |
| b      | 0.64        | 0.89  | .025      | .035 |       |
| b1     | 0.65        | 0.79  | .025      | .031 | 7     |
| b2     | 0.76        | 1.14  | .030      | .045 |       |
| b3     | 4.95        | 5.46  | .195      | .215 | 4     |
| c      | 0.46        | 0.61  | .018      | .024 |       |
| c1     | 0.41        | 0.56  | .016      | .022 | 7     |
| c2     | 0.46        | 0.89  | .018      | .035 |       |
| D      | 5.97        | 6.22  | .235      | .245 | 6     |
| D1     | 5.21        | -     | .205      | -    | 4     |
| E      | 6.35        | 6.73  | .250      | .265 | 6     |
| E1     | 4.32        | -     | .170      | -    | 4     |
| e      | 2.29 BSC    |       | .090 BSC  |      |       |
| H      | 9.40        | 10.41 | .370      | .410 |       |
| L      | 1.40        | 1.78  | .055      | .070 |       |
| L1     | 2.74 BSC    |       | .108 REF. |      |       |
| L2     | 0.51 BSC    |       | .020 BSC  |      |       |
| L3     | 0.89        | 1.27  | .035      | .050 | 4     |
| L4     | -           | 1.02  | -         | .040 |       |
| L5     | 1.14        | 1.52  | .045      | .060 | 3     |
| Ø      | 0°          | 10°   | 0°        | 10°  |       |
| Ø1     | 0°          | 15°   | 0°        | 15°  |       |
| Ø2     | 25°         | 35°   | 25°       | 35°  |       |

LEAD ASSIGNMENTS

HEXFET

- 1.- GATE
- 2.- DRAIN
- 3.- SOURCE
- 4.- DRAIN

IGBT & CoPAK

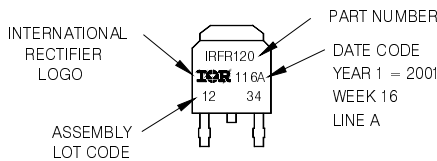
- 1.- GATE
- 2.- COLLECTOR
- 3.- EMITTER
- 4.- COLLECTOR

## D-Pak (TO-252AA) Part Marking Information

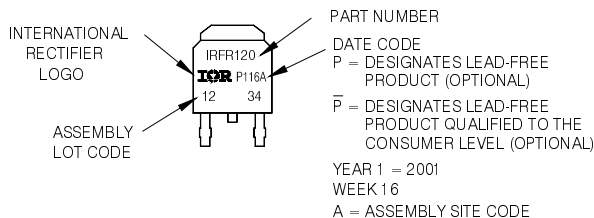
EXAMPLE: THIS IS AN IRFR120  
WITH ASSEMBLY  
LOT CODE 1234  
ASSEMBLED ON WW 16, 2001  
IN THE ASSEMBLY LINE 'A'

Note: 'P' in assembly line position  
indicates 'Lead-Free'

'P' in assembly line position indicates  
'Lead-Free' qualification to the consumer-level



OR

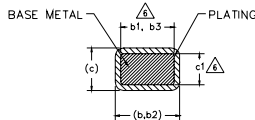
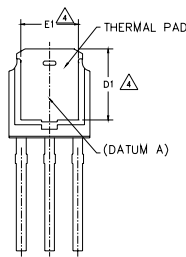
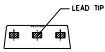
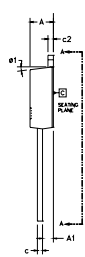
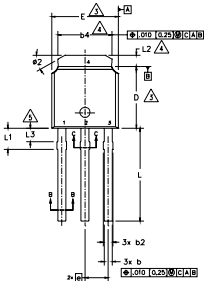


Note: For the most current drawing please refer to IR website at <http://www.irf.com/package/>



## I-Pak (TO-251AA) Package Outline

Dimensions are shown in millimeters (inches)



SECTION B-B & C-C

NOTES:

- 1.- DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994
- 2.- DIMENSION ARE SHOWN IN INCHES [MILLIMETERS].
- 3.- DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED .005 [0.13] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.
- 4.- THERMAL PAD CONTOUR OPTION WITHIN DIMENSION b4, L2, E1 & D1.
- 5.- LEAD DIMENSION UNCONTROLLED IN L3.
- 6.- DIMENSION b1, b3 & c1 APPLY TO BASE METAL ONLY.
- 7.- OUTLINE CONFORMS TO JEDEC OUTLINE TO-251AA (Date 06/02).
- 8.- CONTROLLING DIMENSION : INCHES.

| SYMBOL | DIMENSIONS  |      |          |      | NOTES |
|--------|-------------|------|----------|------|-------|
|        | MILLIMETERS |      | INCHES   |      |       |
|        | MIN.        | MAX. | MIN.     | MAX. |       |
| A      | 2.18        | 2.39 | .086     | .094 | 6     |
| A1     | 0.89        | 1.14 | .035     | .045 |       |
| b      | 0.64        | 0.89 | .025     | .035 | 6     |
| b1     | 0.65        | 0.79 | .025     | .031 |       |
| b2     | 0.76        | 1.14 | .030     | .045 | 6     |
| b3     | 0.76        | 1.04 | .030     | .041 |       |
| b4     | 4.95        | 5.46 | .195     | .215 | 4     |
| c      | 0.46        | 0.61 | .018     | .024 | 6     |
| c1     | 0.41        | 0.56 | .016     | .022 |       |
| c2     | 0.46        | 0.89 | .018     | .035 | 3     |
| D      | 5.97        | 6.22 | .235     | .245 |       |
| D1     | 5.21        | -    | .205     | -    | 4     |
| E      | 6.35        | 6.73 | .250     | .265 | 3     |
| E1     | 4.32        | -    | .170     | -    | 4     |
| e      | 2.29 BSC    |      | .090 BSC |      |       |
| L      | 8.89        | 9.65 | .350     | .380 | 4     |
| L1     | 1.91        | 2.29 | .045     | .090 |       |
| L2     | 0.89        | 1.27 | .035     | .050 | 5     |
| L3     | 1.14        | 1.52 | .045     | .060 |       |
| ø1     | 0"          | 15"  | 0"       | 15"  |       |
| ø2     | 25"         | 35"  | 25"      | 35"  |       |

LEAD ASSIGNMENTS

HEXFEET

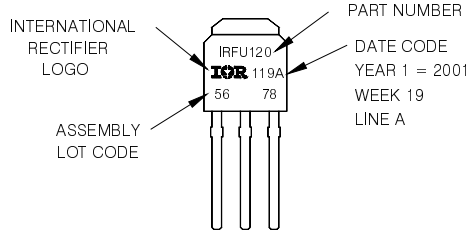
- 1.- GATE
- 2.- DRAIN
- 3.- SOURCE
- 4.- DRAIN

## I-Pak (TO-251AA) Part Marking Information

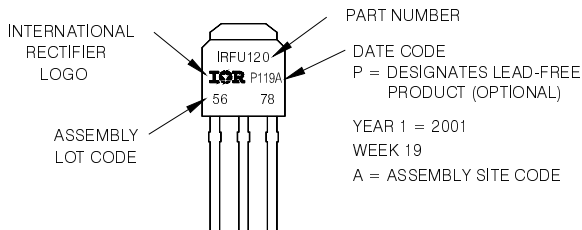
EXAMPLE: THIS IS AN IRFU120  
WITH ASSEMBLY  
LOT CODE 5678  
ASSEMBLED ON WW 19, 2001  
IN THE ASSEMBLY LINE 'A'

Note: 'P' in assembly line position  
indicates Lead-Free

OR



ASSEMBLY  
LOT CODE

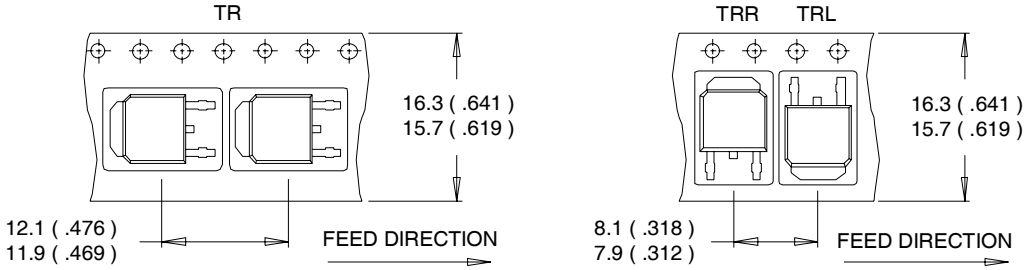


YEAR 1 = 2001  
WEEK 19  
A = ASSEMBLY SITE CODE

Note: For the most current drawing please refer to IR website at <http://www.irf.com/package/>  
[www.irf.com](http://www.irf.com)

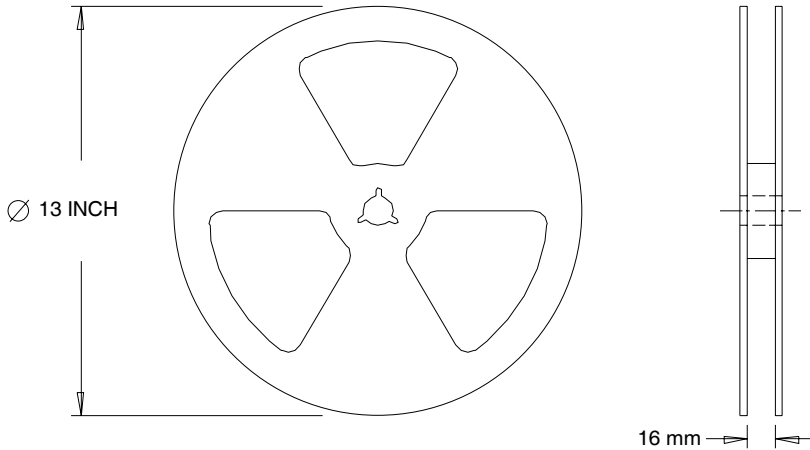
## D-Pak (TO-252AA) Tape & Reel Information

Dimensions are shown in millimeters (inches)



**NOTES :**

1. CONTROLLING DIMENSION : MILLIMETER.
2. ALL DIMENSIONS ARE SHOWN IN MILLIMETERS ( INCHES ).
3. OUTLINE CONFORMS TO EIA-481 & EIA-541.



**NOTES :**

1. OUTLINE CONFORMS TO EIA-481.

Note: For the most current drawing please refer to IR website at <http://www.irf.com/package/>

| Orderable part number | Package Type | Standard Pack |          | Note |
|-----------------------|--------------|---------------|----------|------|
|                       |              | Form          | Quantity |      |
| IRLR8259PBF           | D-PAK        | Tube/Bulk     | 75       |      |
| IRLR8259TRPBF         | D-PAK        | Tape and Reel | 2000     |      |
| IRLU8259PBF           | I-PAK        | Tube/Bulk     | 75       |      |

| Qualification information† |                                                                                                                                                                          |                                    |
|----------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------|
| Qualification level        | Industrial††<br>(per JEDEC JESD47F††† guidelines)                                                                                                                        |                                    |
|                            | Comments: This family of products has passed JEDEC's Industrial qualification. IR's Consumer qualification level is granted by extension of the higher Industrial level. |                                    |
| Moisture Sensitivity Level | D-PAK                                                                                                                                                                    | MSL1<br>(per JEDEC J-ST D-020D†††) |
|                            | I-PAK                                                                                                                                                                    | Not applicable                     |
| RoHS compliant             | Yes                                                                                                                                                                      |                                    |

† Qualification standards can be found at International Rectifier's web site <http://www.irf.com/product-info/reliability>

†† Higher qualification ratings may be available should the user have such requirements. Please contact your

International Rectifier sales representative for further information: <http://www.irf.com/whoto-call/salesrep/>

††† Applicable version of JEDEC standard at the time of product release.

**Notes:**

- ① Repetitive rating; pulse width limited by max. junction temperature.
- ② Starting  $T_J = 25^\circ\text{C}$ ,  $L = 0.48\text{mH}$ ,  $R_G = 25\Omega$ ,  $I_{AS} = 17\text{A}$ .
- ③ Pulse width  $\leq 400\mu\text{s}$ ; duty cycle  $\leq 2\%$ .
- ④ Calculated continuous current based on maximum allowable junction temperature.  
 Package limitation current is 42A.
- ⑤ When mounted on 1" square PCB (FR-4 or G-10 Material). For recommended footprint and soldering techniques refer to application note #AN-994.

Data and specifications subject to change without notice.

International  
**IR** Rectifier

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